
Designing pinning in coated conductors with a view to accelerator magnets

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Acknowledgments



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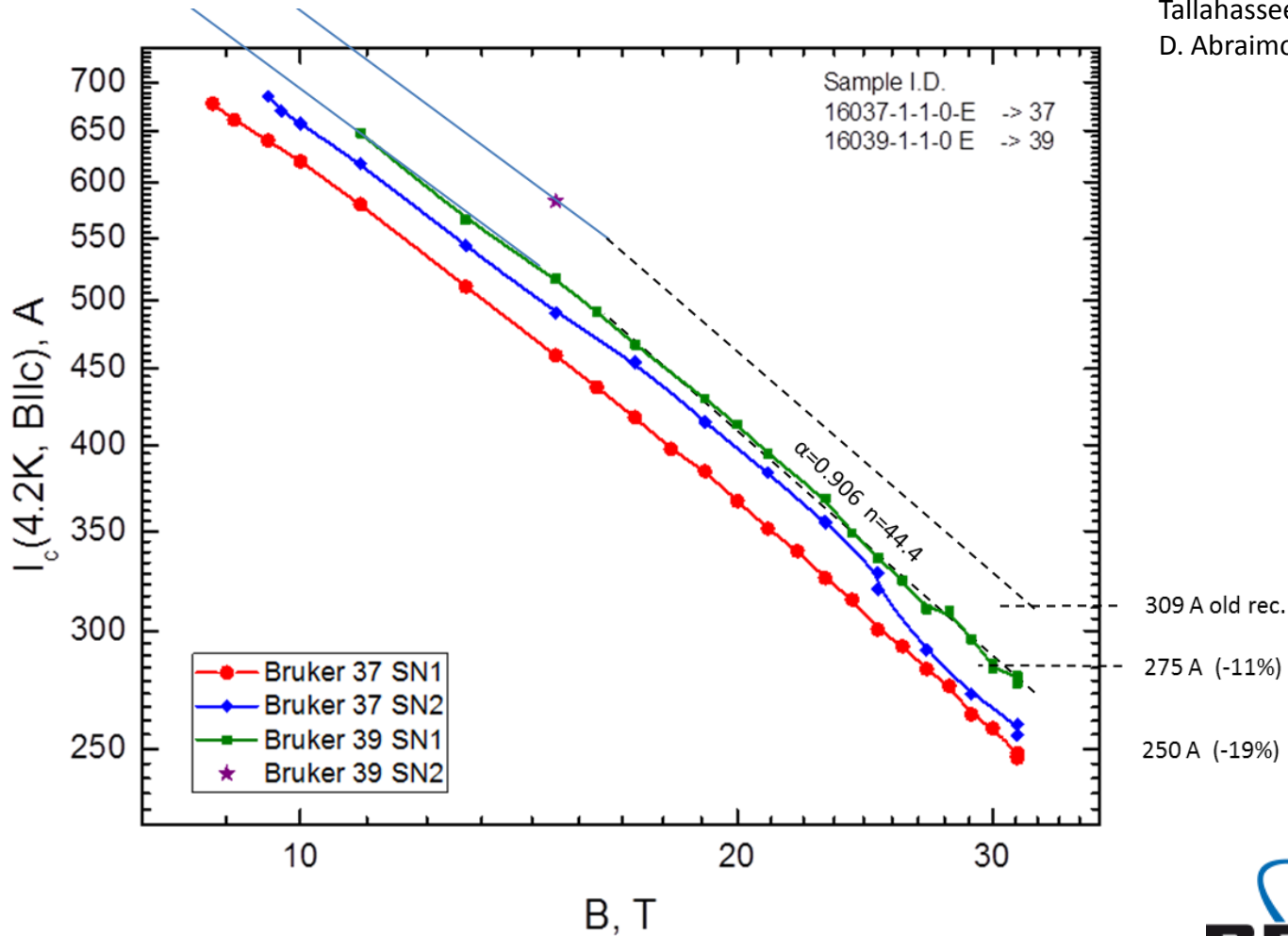


REBCO excellent for generating high fields

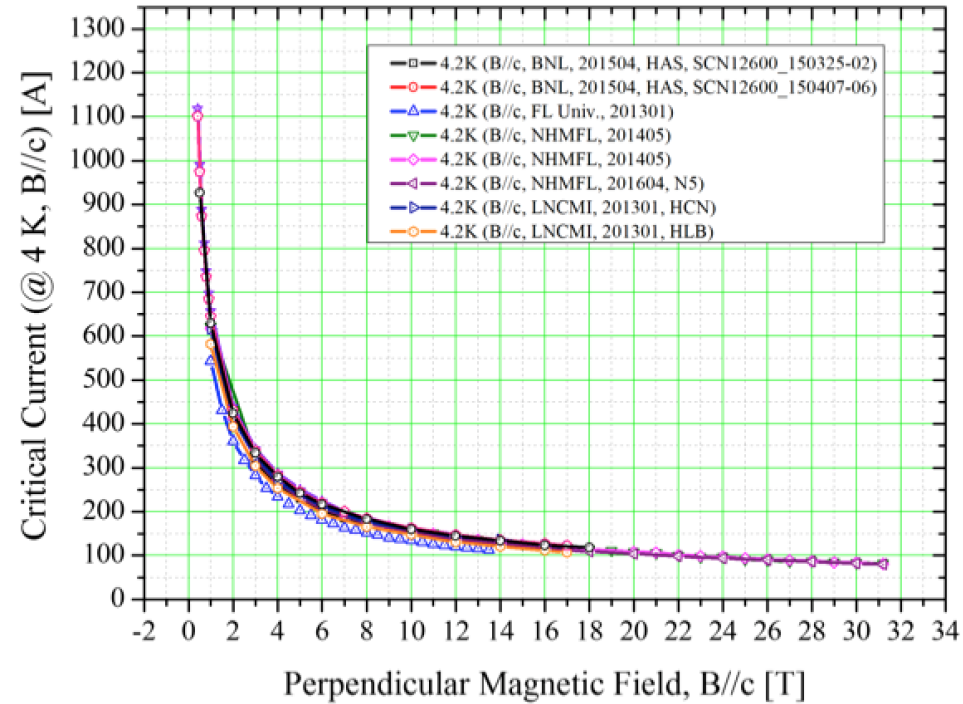
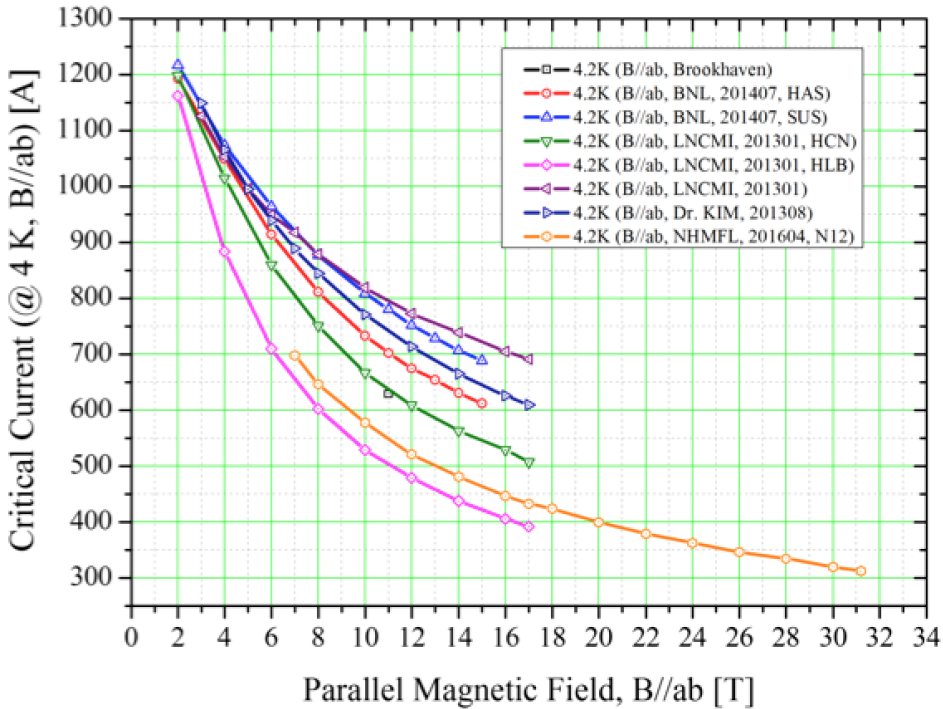
- Today's REBCO CC is an amazing conductor for high field magnets
 - 40 T today, 3 all superconducting 26-27 T magnets demonstrated in K, J and USA, 32 T expected soon
 - No Insulation (NI) is allowing (small) magnets to operate at the 1000 A/mm² level safely
- 4 K magnets deliver “Pull” – **but can they deliver profitability?**

Bruker: Processing up-scaling: 602-609 m long tapes: Tapes have 'mixed' pinning centres

Recent measurements at
Tallahassee, Jan 24, 2017,
D. Abraimov, D. Larbalestjer



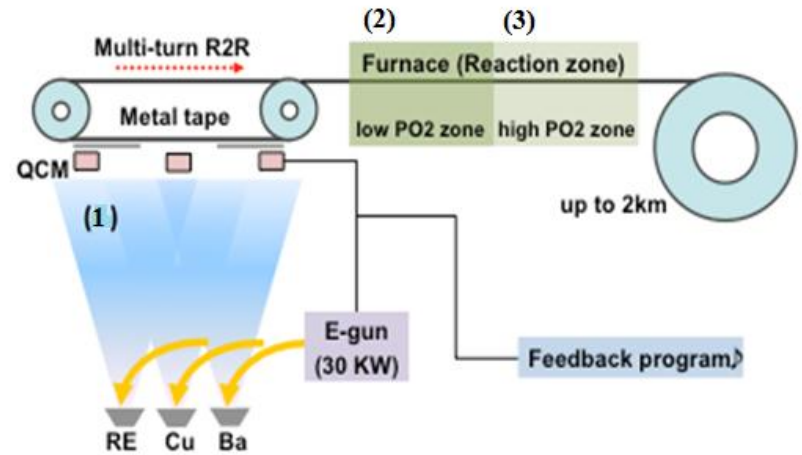
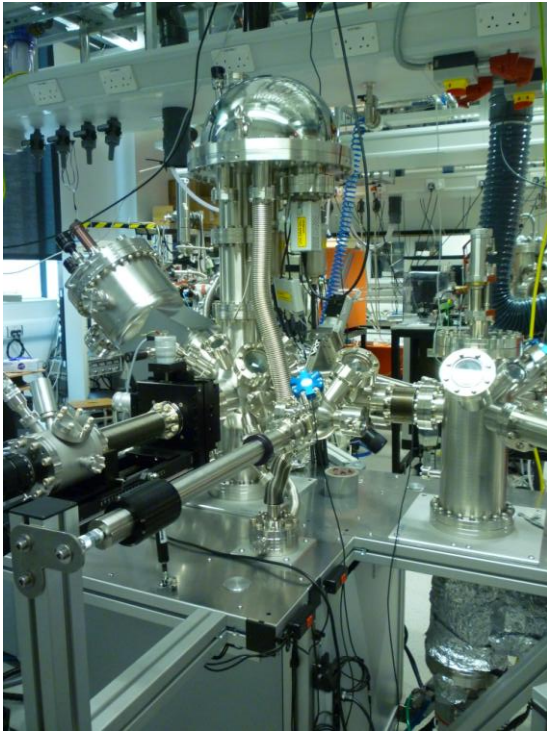
In field properties at 4.2 K upto 31 T (without APC)



- Large variation @ $B// ab$ -plane.
- Homogeneous and small slope at high field (> 15 T) @ $B// c$.
- All the data were measured with 4 mm width tape.



I will discuss pinning developed with PLD but this is applicable also to physical vapour, e.g. e-beam, MOCVD

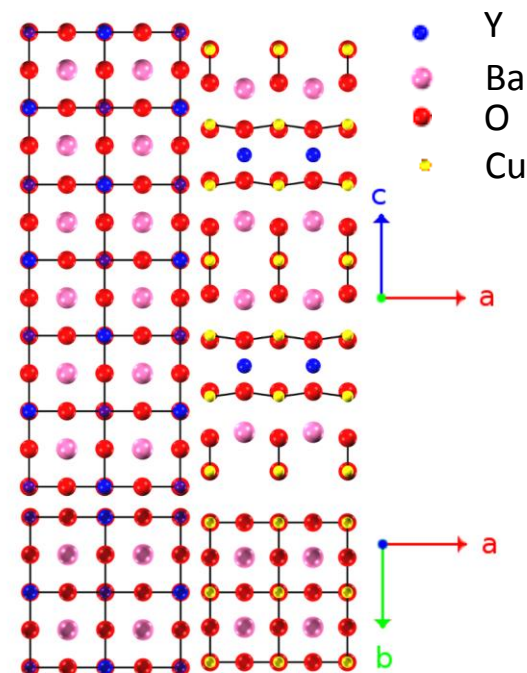


- (1) very low PO₂ zone: 10⁻⁵ Torr, amorphous film
- (2) lower PO₂ zone: 30 mTorr, < 5 sec, Gd₂O₃ + L
- (3) higher PO₂ zone: 100 mTorr, <60 Sec, 123 phase

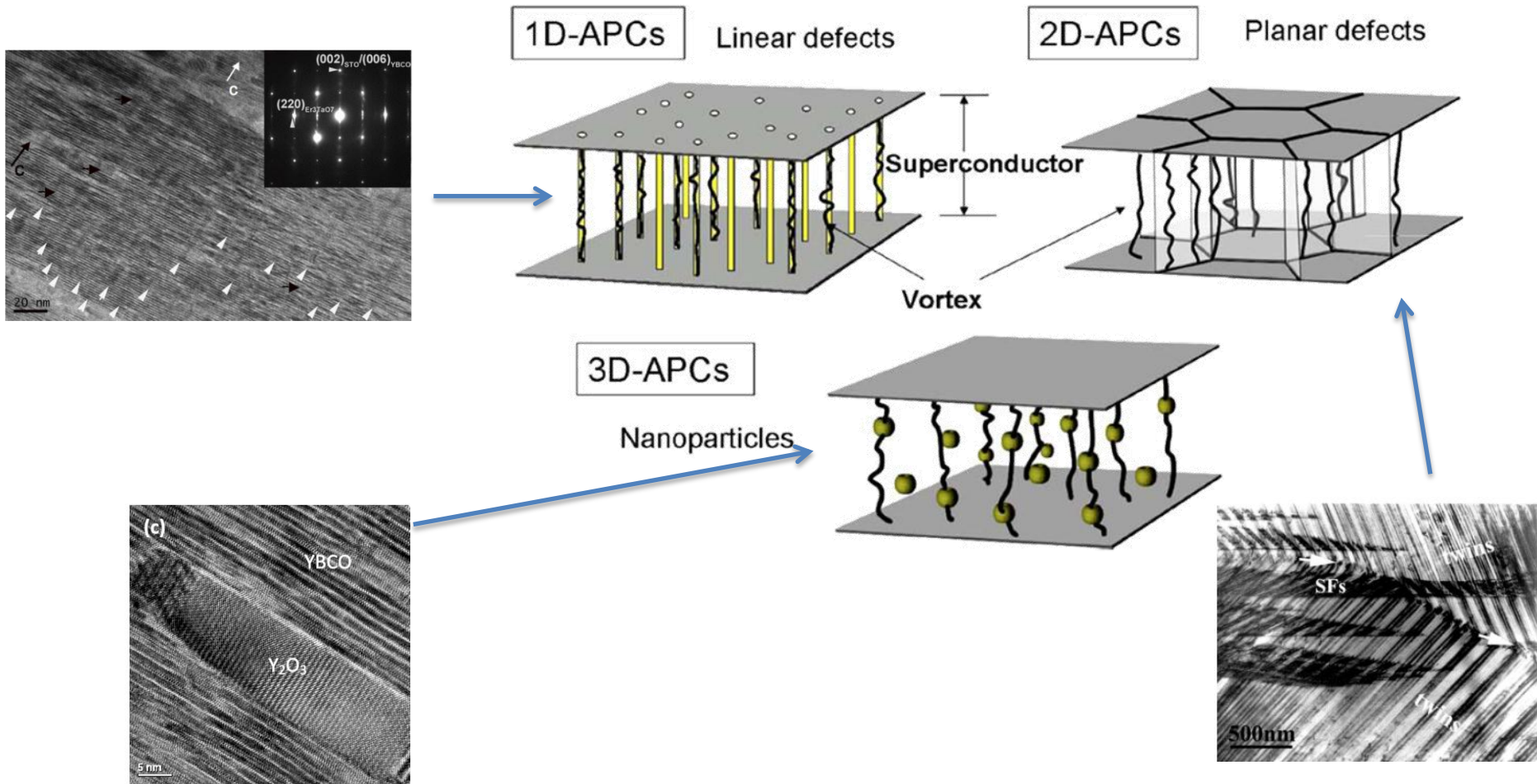


Choosing your pinning additions (perovskites based on Ba, rare earth oxides)

1 Hydrogen																2 Helium																			
3 Lithium		4 Beryllium												5 Boron		6 Carbon		7 Nitrogen		8 Oxygen		9 Fluorine		10 Neon											
11 Sodium		12 Magnesium												13 Aluminium		14 Silicon		15 Phosphorus		16 Sulfur		17 Chlorine		18 Argon											
19 Potassium		20 Calcium		21 Scandium		22 Titanium	23 Vanadium	24 Chromium		25 Manganese		26 Iron		27 Cobalt		28 Nickel		29 Copper		30 Zinc		31 Gallium		32 Germanium		33 Arsenic		34 Selenium		35 Bromine		36 Krypton			
37 Rubidium		38 Strontium		39 Yttrium		40 Zirconium	41 Niobium	42 Molybdenum		43 Technetium		44 Ruthenium		45 Rhodium		46 Palladium		47 Silver		48 Cadmium		49 Indium		50 Tin		51 Antimony		52 Tellurium		53 Iodine		54 Xenon			
55 Cesium		56 Barium		57-70 Lanthanides		71 Lanthanum	72 Cerium	73 Praseodymium	74 Neodymium		75 Promethium		76 Samarium		77 Europium		78 Gadolinium		79 Terbium		80 Dysprosium		81 Holmium		82 Erbium		83 Thulium		84 Ytterbium		85 Lutetium		86 Ytterbium		
87 Francium		88 Radium		89-102 Actinides		103 Rutherfordium	104 Rhenium	105 Dubnium	106 Seaborgium		107 Bohrium		108 Hassium		109 Meitnerium		110 Darmstadtium		111 Roentgenium		112 Copernicium		113 Nihonium		114 Flerovium		115 Moscovium		116 Livermorium		117 Tennessine		118 Oganesson		
7 Lanthanides																8 Actinides																			
57 Lanthanum		58 Cerium		59 Praseodymium		60 Neodymium		61 Promethium		62 Samarium		63 Europium		64 Gadolinium		65 Terbium		66 Dysprosium		67 Holmium		68 Erbium		69 Thulium		70 Ytterbium		71 Lutetium		72 Ytterbium		73 Hafnium		74 Tantalum	
89 Actinium		90 Thorium		91 Protactinium		92 Uranium		93 Neptunium		94 Plutonium		95 Americium		96 Curium		97 Berkelium		98 Californium		99 Einsteinium		100 Fermium		101 Mendelevium		102 Nobelium		103 Lawrencium		104 Rutherfordium		105 Dubnium			



The different types of pinning centres in PVD-grown films



H Zhou et al, Sup Sci Tech, Vol 22, 2009

J Gazquez et al, Sup Sci Tech, Vol 25, 2012

Matsumoto et al, IEEE Trans. Appl. Supercon, 19 (3) 2009

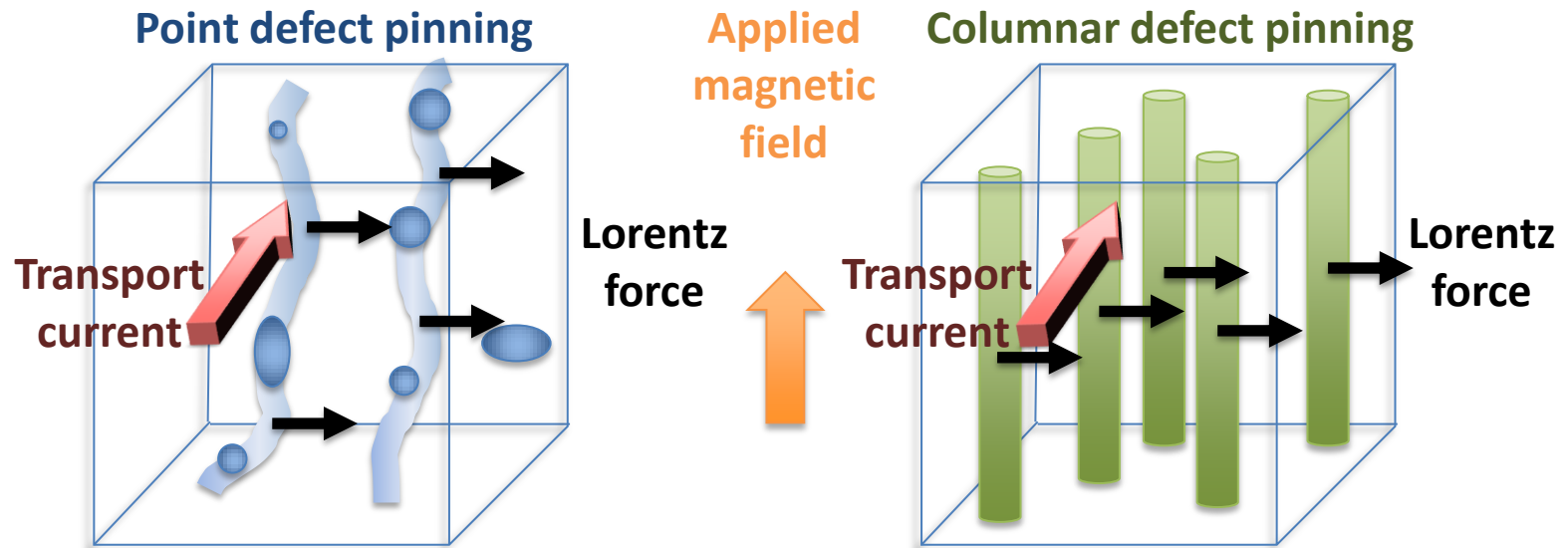
Designing the pinning landscape- what's important?

Geometry, distribution, strain with matrix

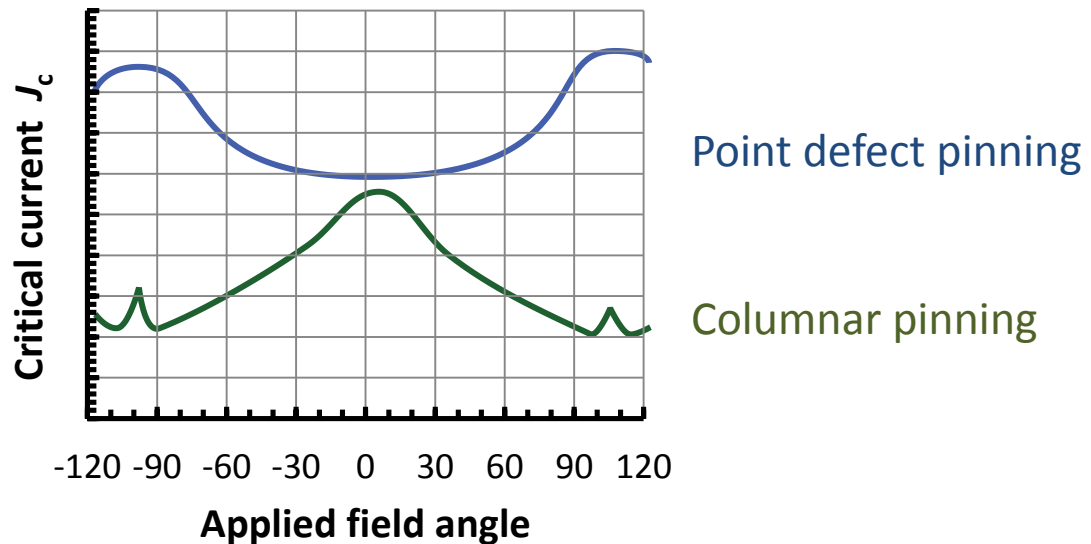
- Chemistry of pinning addition (or combination of additions)
- % addition

- Q. How do processing conditions (growth method, growth rate, growth temperature) influence above?
- A. Need to understand basic materials chemistry *and* nucleation and growth

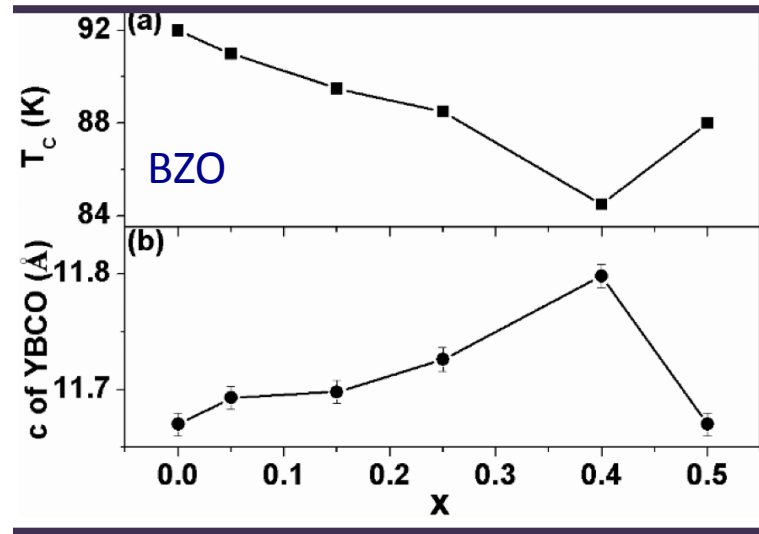
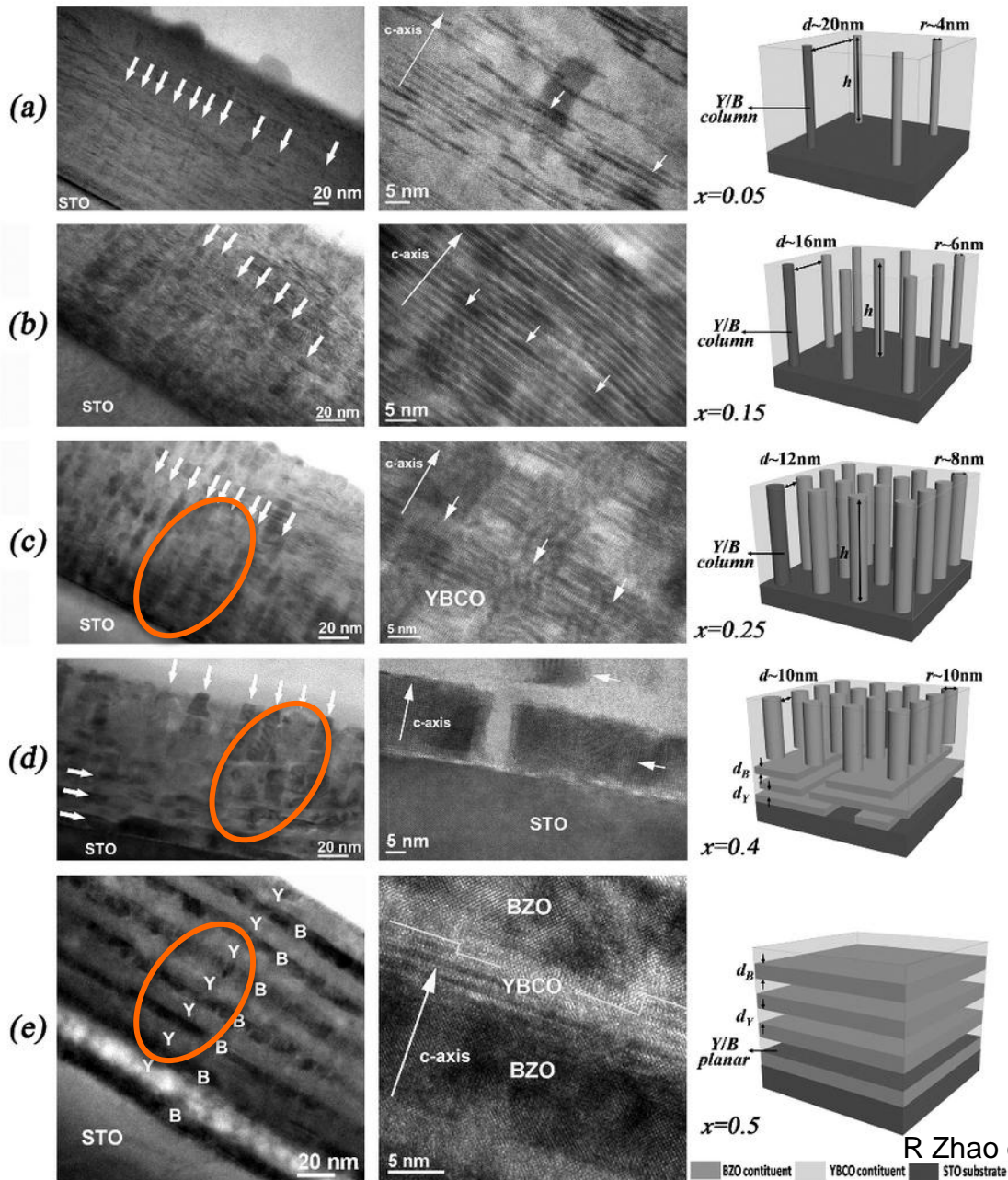
Defect types and how they behave with H ($\sim 77\text{K}$)



For higher field applications things are different. Point defects very important. Mixed microstructure good for a wide range of temperature and field.



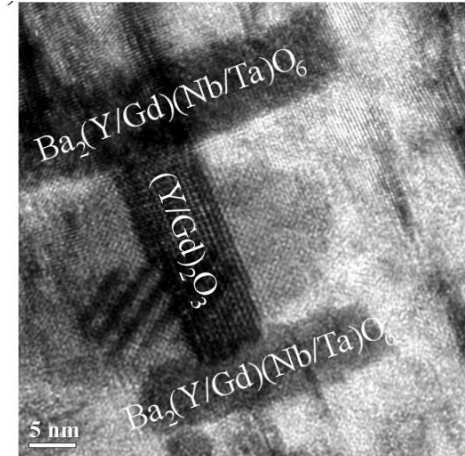
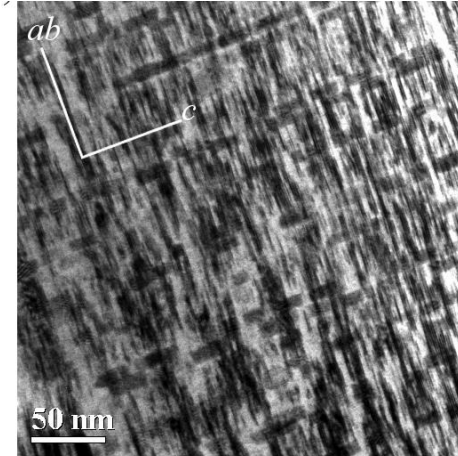
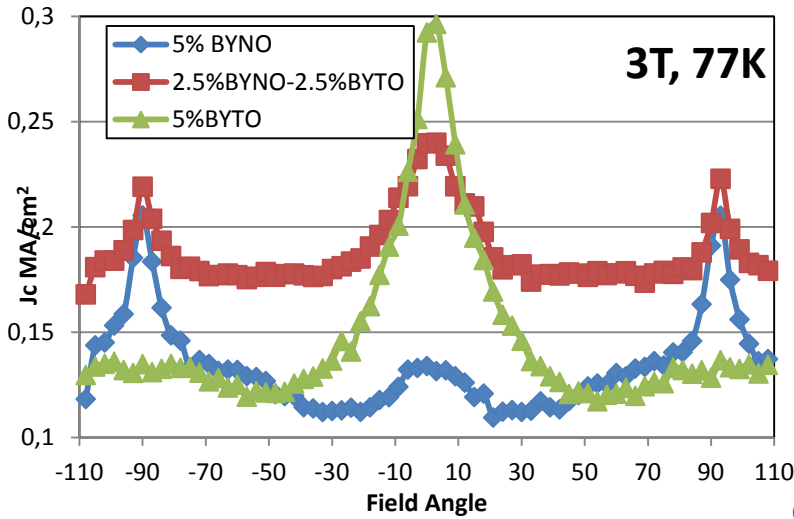
Mixed defect structure can be engineered by playing with thermodynamics and kinetics



Higher % additions should be very good for higher field, lower temperature applications.

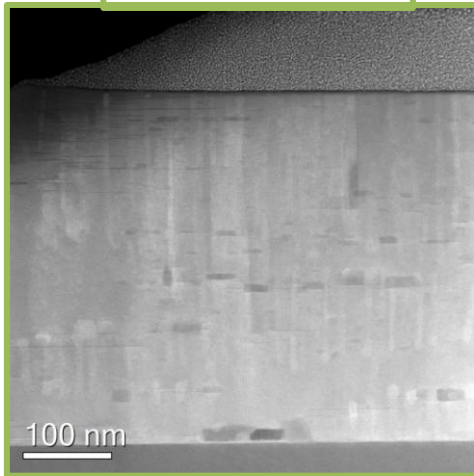
R Zhao et al *Advanced Functional Materials*. Vol. 33. 5240, 2014
 Y Zhu et al, *J Mater Res*, Vol 27, No 13, 2012
 C.V. Varanasi et al, *J Mater Res*, Vol 23, No 12, 2008

At 77K, BYNO and BYTO columns + RE₂O₃ gives superior angular properties over a wide angular range

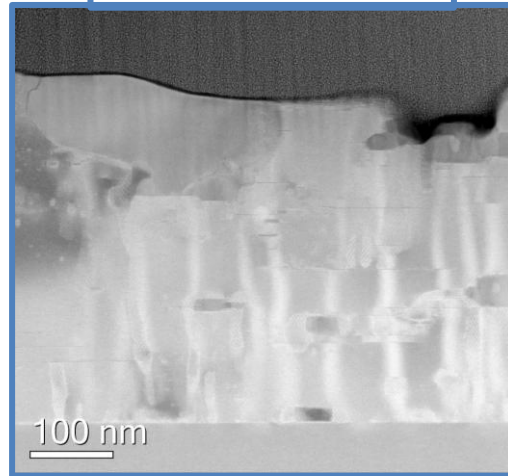


G. Ercolano et al. Superconductor Science & Technology. Sep 2011;24(9)

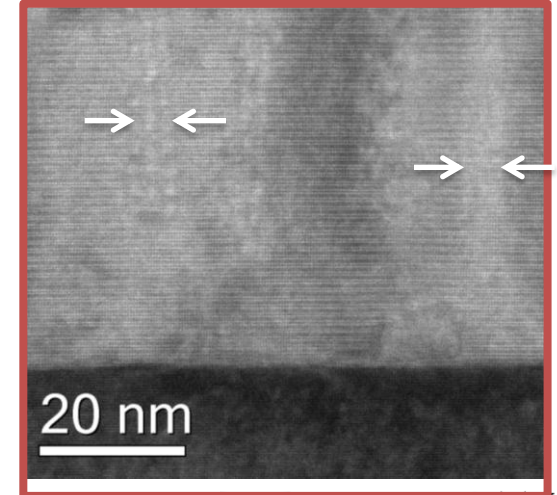
BYTO, 5 nm



BYNO, 10-20 nm



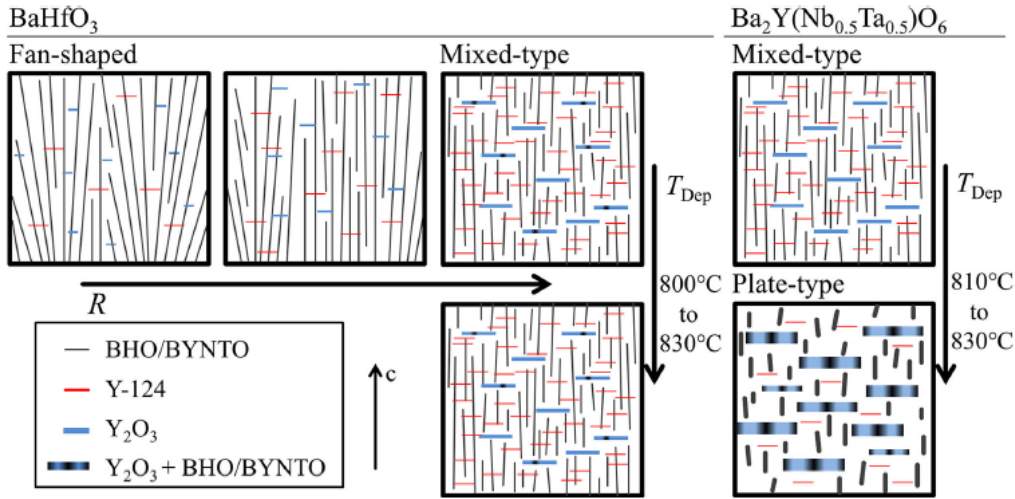
BYNTO, ~ 8 nm



A. Melendin, S. van Tendeloo, UA

Good control of variety of pinning nanostructures for 77K optimisation on metal

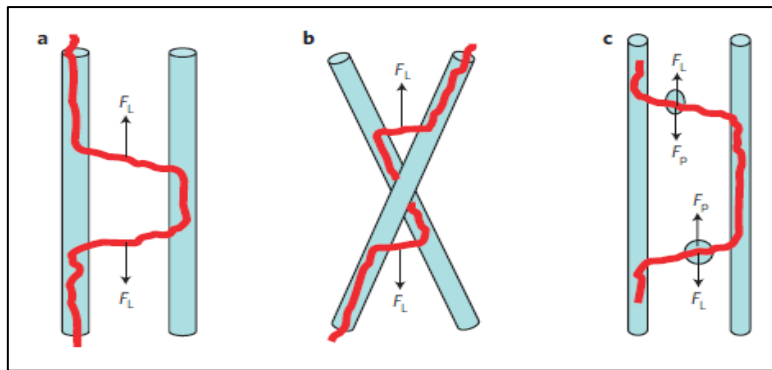
ENEA, UCAM, KIT



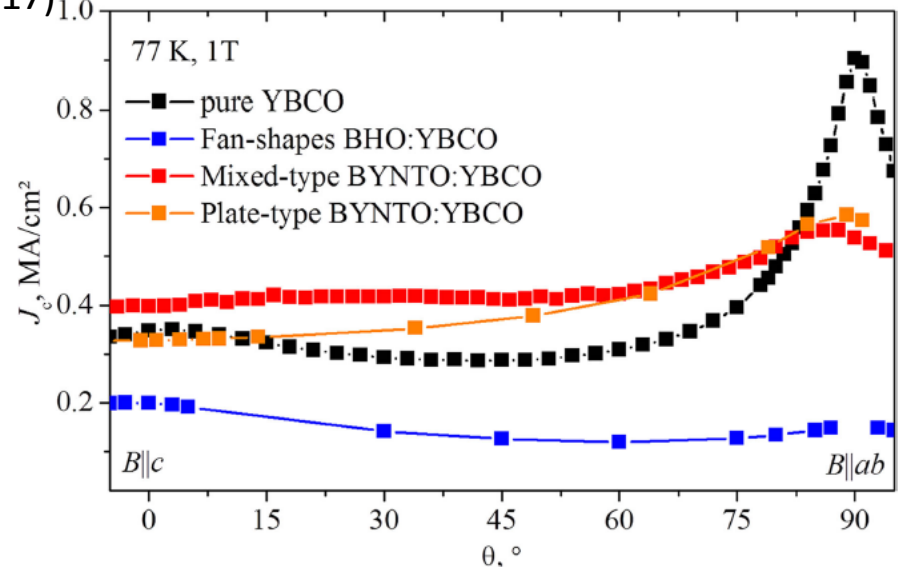
Control shape/distribution by changing deposition rate and temperature (on ABAD YSZ), > 1 μm thickness



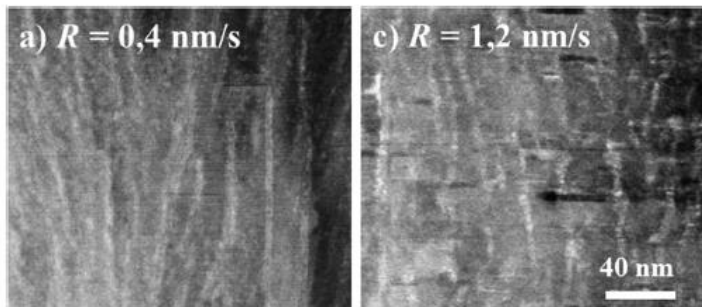
M Sieger et al, IEEE Tran. Appl. Supercon. 27,4, (2017)



B Maiorov et al, Nat. Mat. (8) (2009)

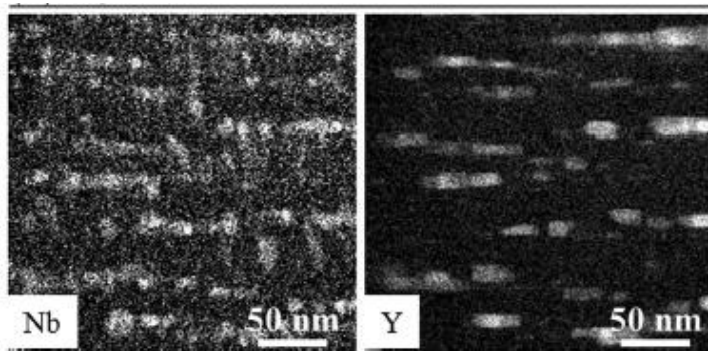


Good control of variety of pinning nanostructures for 77K optimisation

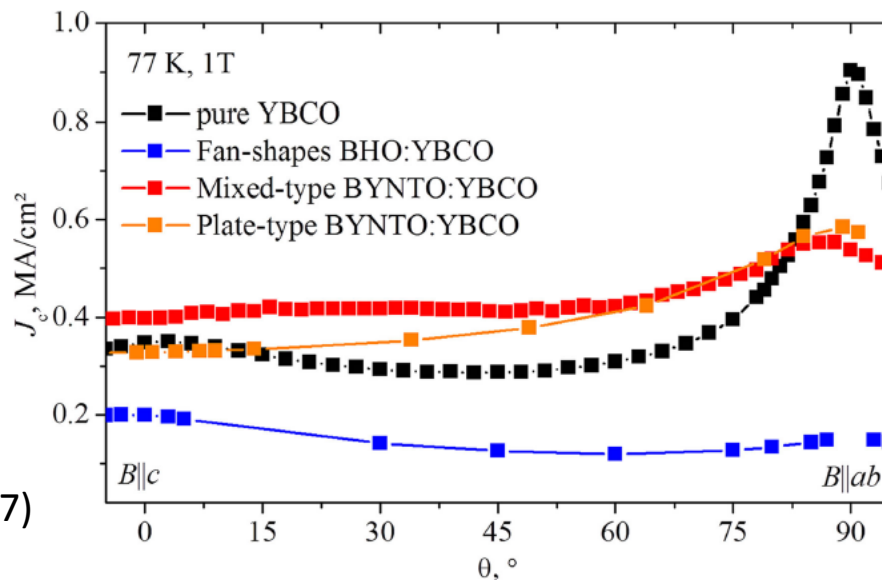


Splayed columns

Mixed columns and plates

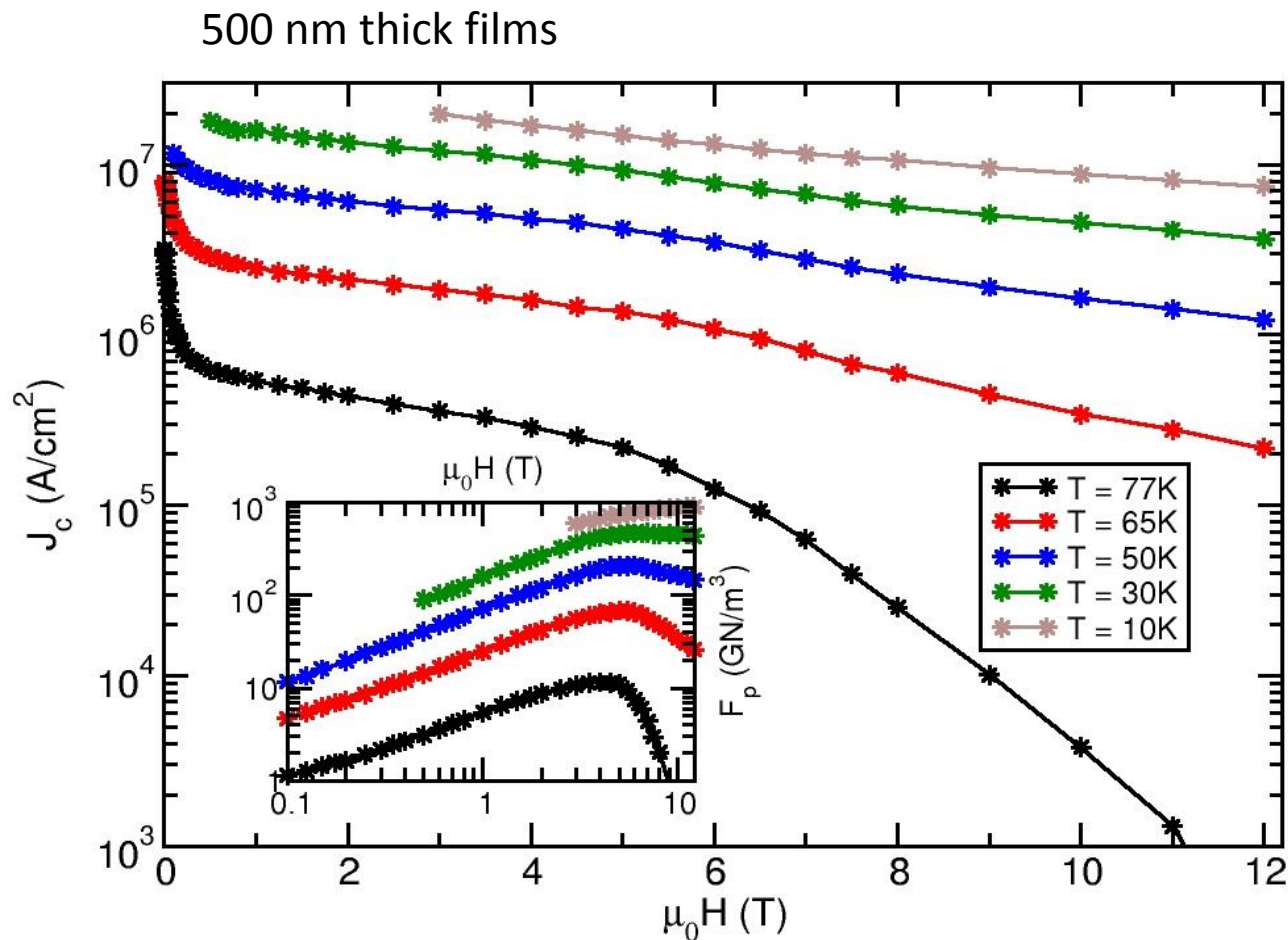


Plates



M Sieger et al, IEEE Tran. Appl. Supercon. 27,4, (2017)

BYNTO behaves very well over a wide field regime. Up to 10K, 12T, the data looks very good, but still not studied at very high fields or 4K



Kinetics of pinning addition growth most important for dimensional control.

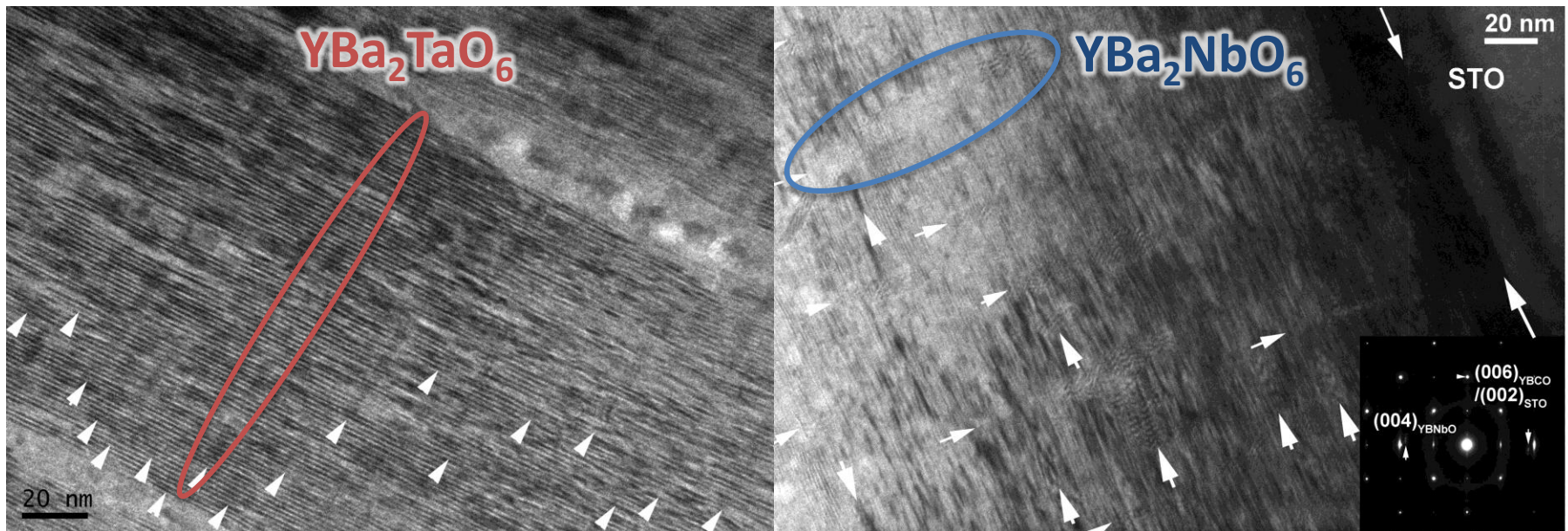
4 important factors: Binary oxide m.p., complexity of phase, % addition, whether source is in film

Comparing Nb, Sn, Ta, Zr which form the perovskite pinning centres:

Lattice parameters similar (4.20-4.22 Å) as are ionic radii (Nb being smallest (0.64 Å)).

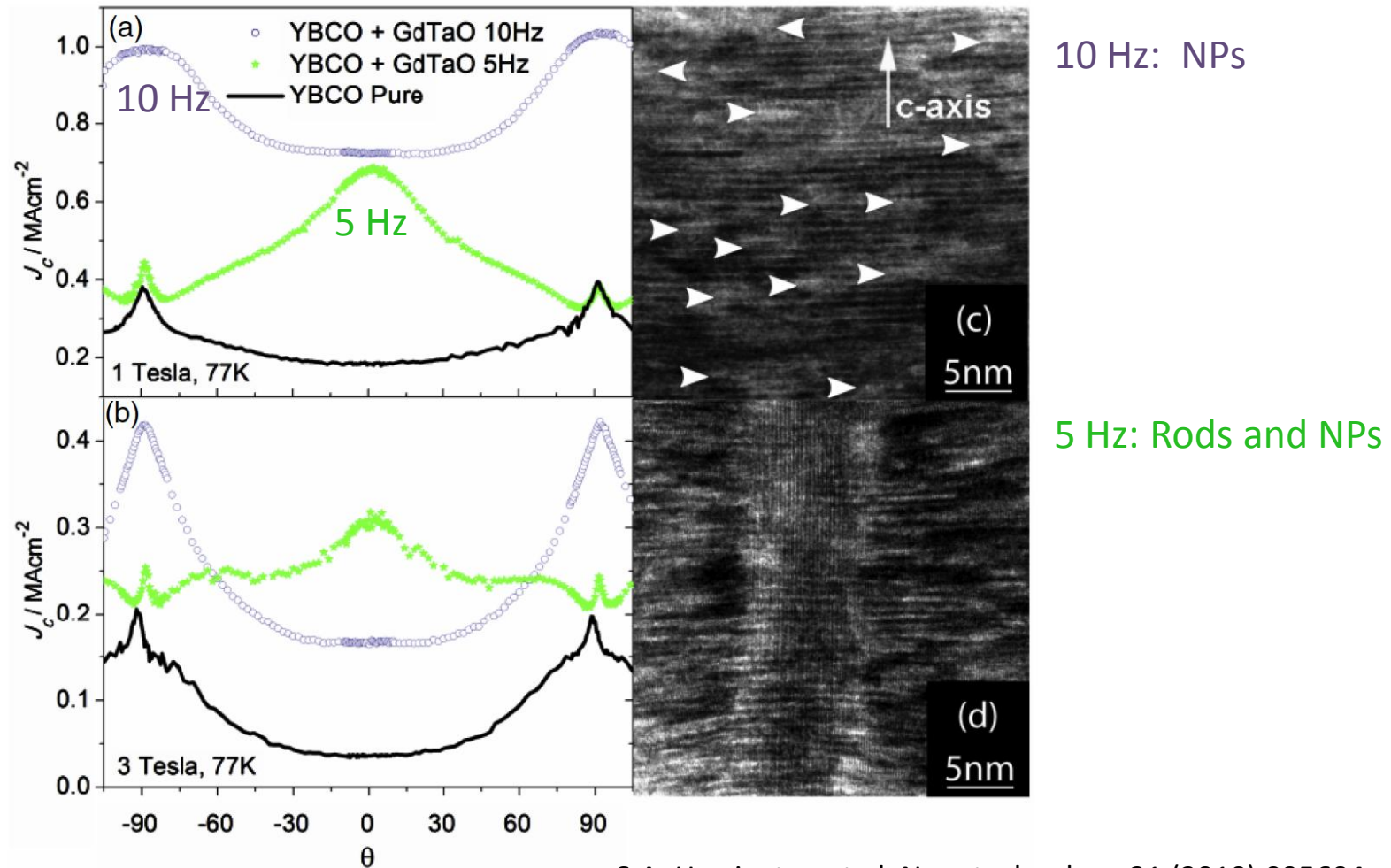
Melting points (°C): **Nb₂O₅** = 1512C , **SnO₂** = 1630C , **Ta₂O₅** = 1872C , **ZrO₂** = 2715C

Tantalate is the finest, since creating DP rather than SP is kinetically limiting.



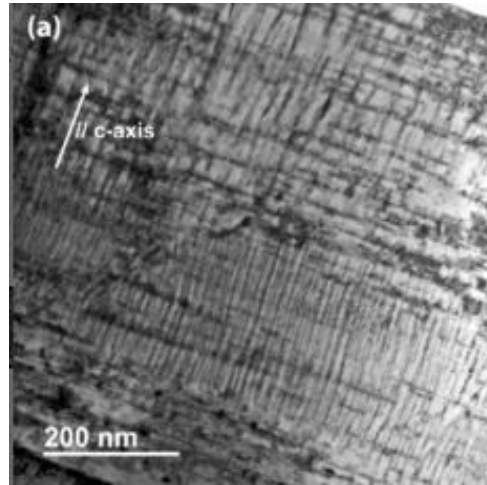
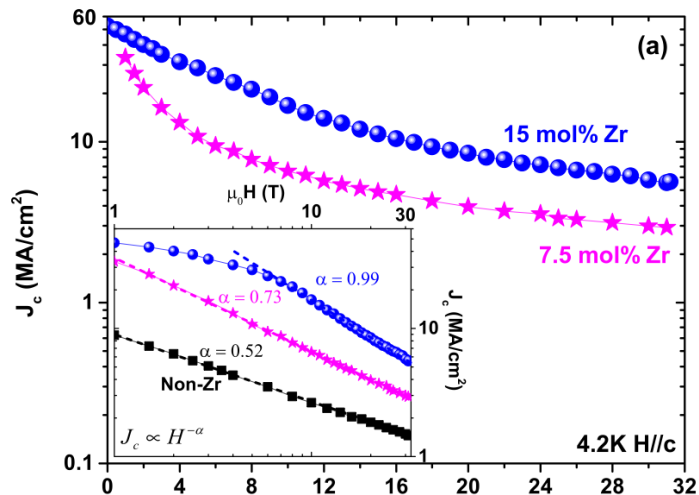
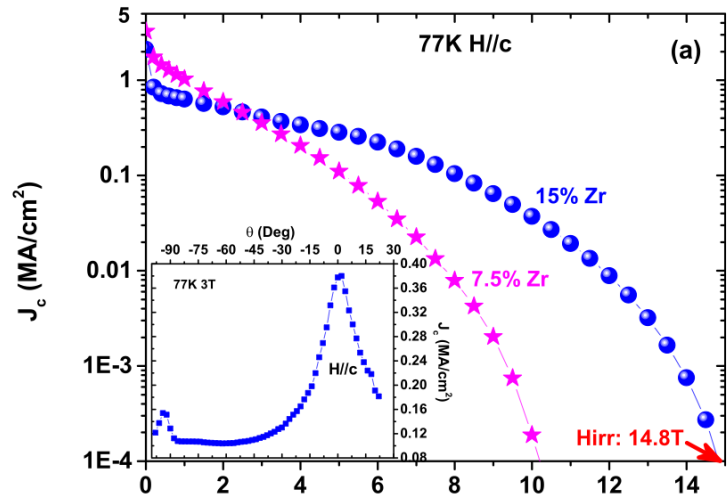
For very high fields, we need dense, very fine, random NP

Tantalates ideal as m.p. of Ta_2O_5 high and DP (“poor kinetics”) → hence low mobility



S.A. Harrington et al. Nanotechnology 21 (2010) 095604

High levels of Zr work well both for 77K and 4.2K
A lot of other pinning additions should do so as well



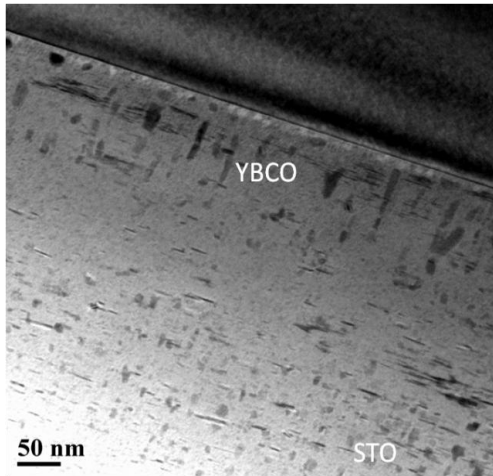
Zr addition

Off stoichiometry

BaZrO₃ forms leaving
matrix RE₂O₃ and
CuO rich

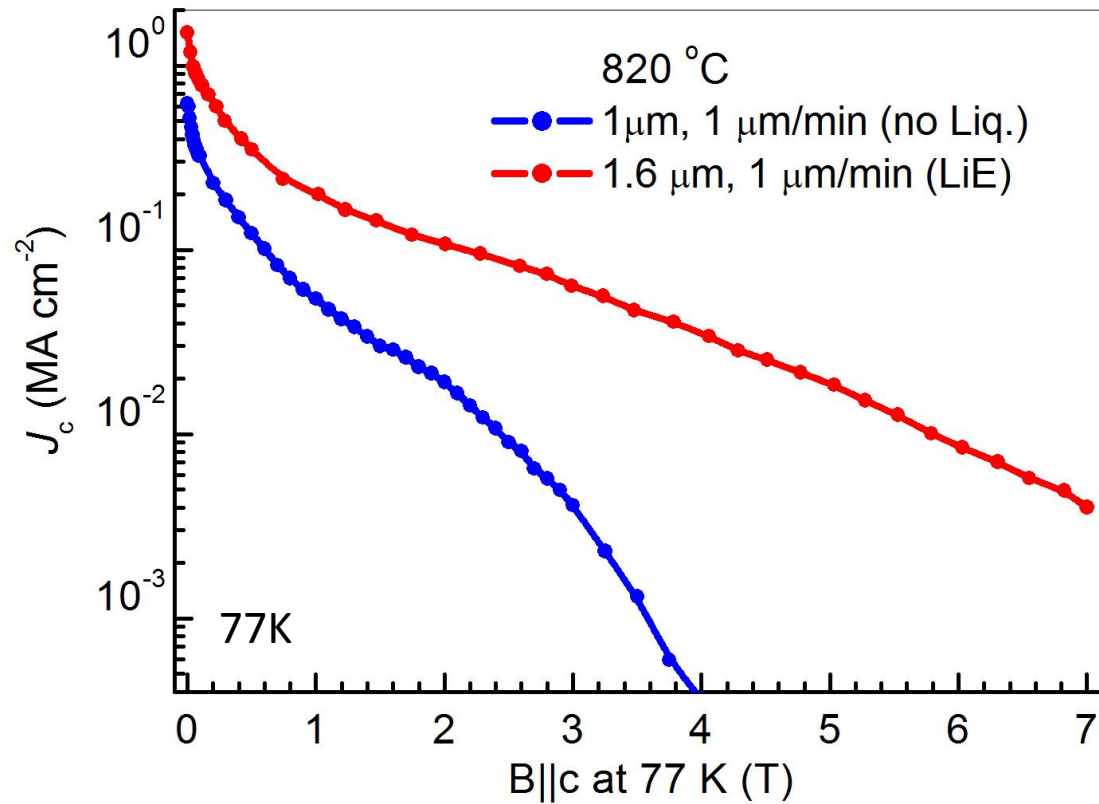
Xu et al. APL Materials 2 04611 (2014)

Finally: **Cost of conductor very important. Need fast-grown conductors.** This can be done with liquid additions while still maintaining strong pinning



BYNO still self assembles in presence of liquid at very fast growth. An *additional* 'poor kinetics' phase needed for high field, low T

BYNO + liquid-in-epitaxy (LiE) processed YBCO. Good 77K performance at very high growth rates (1 $\mu\text{m}/\text{min}$)



Next stages

Much work to be done for low T, high field applications. Most work has been done for 77K, but the regimes are very different.

- Pinning centre size and distribution influenced by their chemistry.
- Mix of random and correlated is good for most regimes of field and temperature below 77K and at high fields.
- Very fine nanostructures needed. This means high melting point binary precursors of the perovskite B-site ion. Otherwise, you need to grow too fast and that is detrimental to YBCO crystallinity.
- High performance, cost-effective conductors are essential. Strong pinning and reduced cost by fast liquid growth should be considered *together*.